

isc Silicon NPN Darlington Power Transistor

2SD1024

DESCRIPTION

- · Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)}= 100V(Min)
- · High DC Current Gain
 - : h_{FE}= 1500(Min) @I_C= 5A
- Low Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

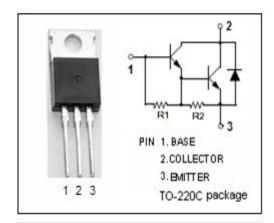
• Designed for general purpoe amplifier applications.

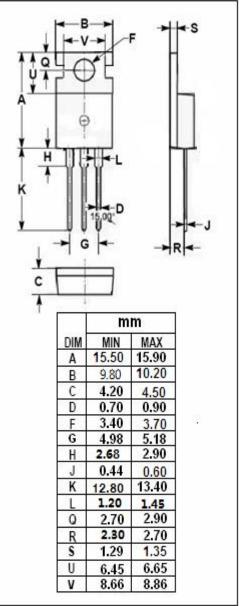
ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	100	V
Vceo	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	8	А
ICP	Collector Current-Peak	12	Α
I _B	Base Current-Continuous	0.5	А
I _{BM}	Base Current-Peak	1	А
Pc	Collector Power Dissipation @ Tc=25℃	50	W
TJ	Junction Temperature	150	$^{\circ}\!$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	2.5	°C/W







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

1c=25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 6mA			1.5	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 6mA			2.0	V			
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E =0			0.1	mA			
I _{CEO}	Collector Cutoff Current	V _{CE} = 100V; I _B =0			0.1	mA			
І _{ЕВО}	Emitter Cutoff Current	V _{EB} = 7V; I _C =0			5	mA			
h _{FE}	DC Current Gain	I _C = 5A; V _{CE} = 3V	1500		30000				
f⊤	Current-Gain—Bandwidth Product	I _C = 0.8A; V _{CE} = 10V		20		MHz			
Switching times									
t _{on}	Turn-on Time				2.0	μS			
t _{stg}	Storage Time	I_{C} = 8A, I_{B1} = I_{B2} = 8mA R_{L} = 3 Ω ; V_{BB2} = 4V			5.0	μS			
t _f	Fall Time				3.0	μS			

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